



Istituto Nazionale di Fisica Nucleare
SEZIONE DI TORINO



Principle of operation of an innovative new sensor for neutron detection based on resistive AC coupled LGADs

38th RD50 Workshop

LUCA MENZIO

UNIVERSITÀ DI TORINO-INFN

UFSD group – LISS

Supported by the FARE MIUR Grant

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Introduction

Neutron detection

Neutron detectors are not vertex detectors!

- Lower energies (typically below 10 MeV)
- Low rates and fluxes
- Should be photons insensitive

Neutrons need conversion into charged particles to be detected

- Recoil (high energies)
- Induced fission
- Nuclear capture by elements with $A > 40$ (passive)
- Nuclear capture by light elements



Classification	Energy
Cold	$< 0.012 \text{ eV}$
Thermal	$0.012 \text{ eV} - 0.4 \text{ eV}$
Epithermal	$0.4 \text{ eV} - 0.01 \text{ MeV}$
Fast	$0.01 \text{ MeV} - 20 \text{ MeV}$
High Energy	$> 20 \text{ MeV}$

Field of application: neutron imaging

Neutron Imaging is a radiographic non- destructive method.

It exploits neutrons ability to penetrate materials with attenuation coefficients specific for each material (isotope).

In this field are employed

- cold or thermal neutrons beams
- Fluxes in the order of 10^5 - 10^9 n/(cm²s)

Normally, images are shot using neutron cameras

- Maximum resolution ever achieved of circa 14 μ m, normally around 100 μ m
- Camera integration time is around 1-2 s

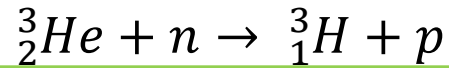


Xrays (top) and neutrons (bottom).
Image taken from PSI website.

How to detect thermal neutrons

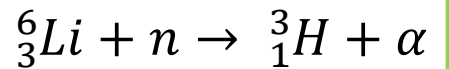
Given the high cross section, traditional methods to detect thermal neutrons rely on neutron capture and subsequential detection of secondary charged particles with scintillators or gases.

Excluding fissionable isotopes and materials which don't provide good neutron-photon discrimination, the main useful thermal capture reactions are



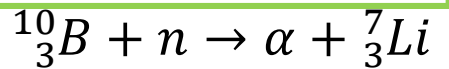
$$Q = 764 \text{ keV}$$

$$5330 \text{ barn @ 25 meV}$$



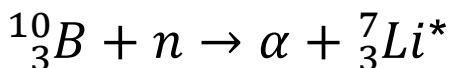
$$Q = 4.78 \text{ MeV}$$

$$940 \text{ barn @ 25 meV}$$



$$Q = 2.79 \text{ MeV}$$

$$3840 \text{ barn @ 25 meV}$$



$$Q = 2.31 \text{ MeV}$$

- High Q-value, good photons rejection
- Solid compounds (i.e. LiF and LiI)
- Easy to enrich – relatively cheap



Most employed with silicon devices

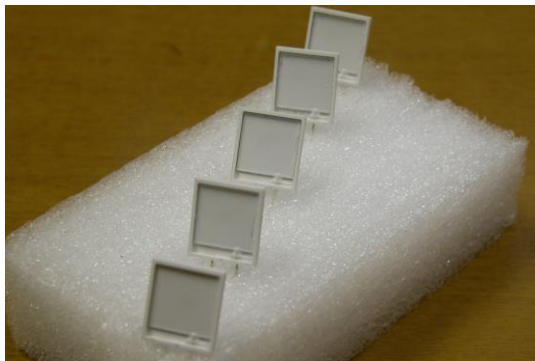
Neutron Detection with Silicon Sensors

Silicon detectors and ^6Li

At INFN LNF (Laboratori Nazionali di Frascati) Roberto Bedogni's team is successfully using a LiF deposition technique to assemble silicon neutron detectors. It consists in:

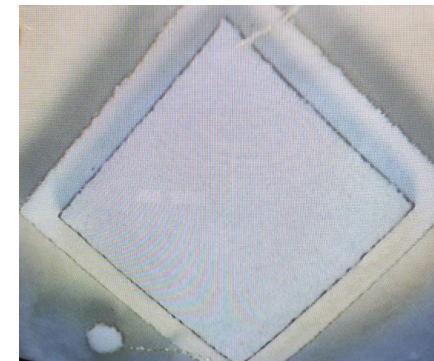
- Suspension with ^6LiF enriched powder
- Evaporation process

The method is quite simple, cheap and provides a good reproducibility



S3590-09 Hamamatsu
Diode

Area 1 cm^2



SgLux UV photodiodes
Silicon carbide

Area 7.2 mm^2

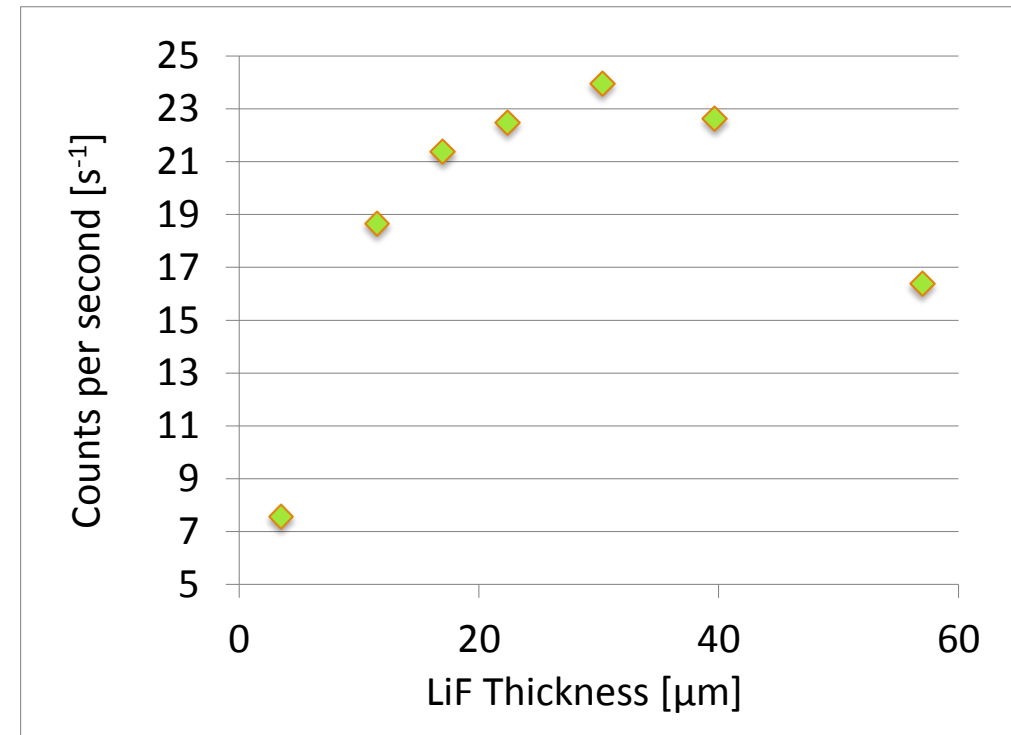
Diodes sensitive to neutrons

The detectors are assembled, wired and tested by the INFN group. The testing is carried out in the Hotnes facility.

Most recently, a set of diodes with ${}^6\text{LiF}$ deposit have been studied and produced for the NCT-WES project.

Both experimental and simulation results show that the maximum efficiency is achieved with **34 μm thick ${}^6\text{LiF}$** deposition on the diode surface

Extremely good for beam monitoring and neutron spectroscopy (inside Bonner Spheres), but not for position and time measurements.

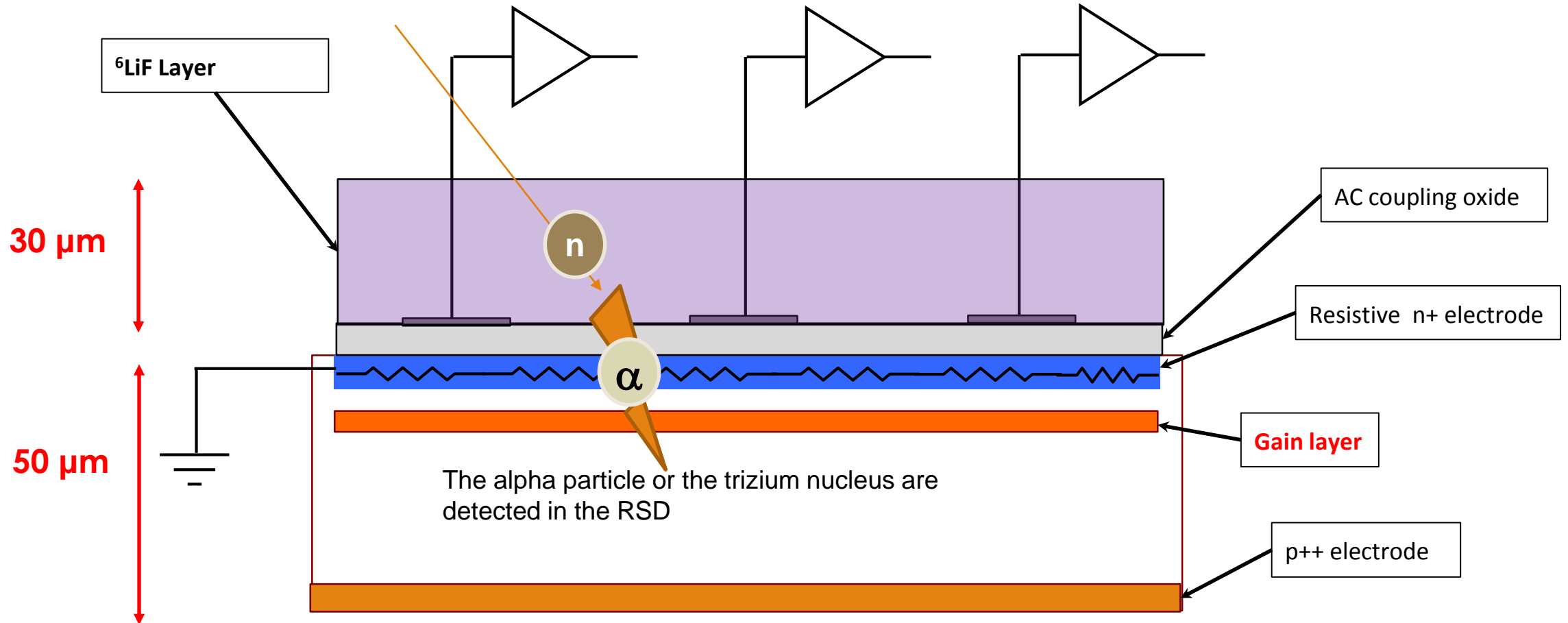


Efficiency results obtained with a LiF coated detector in the Hotnes facility.

Our Project: RSDs for neutron detection

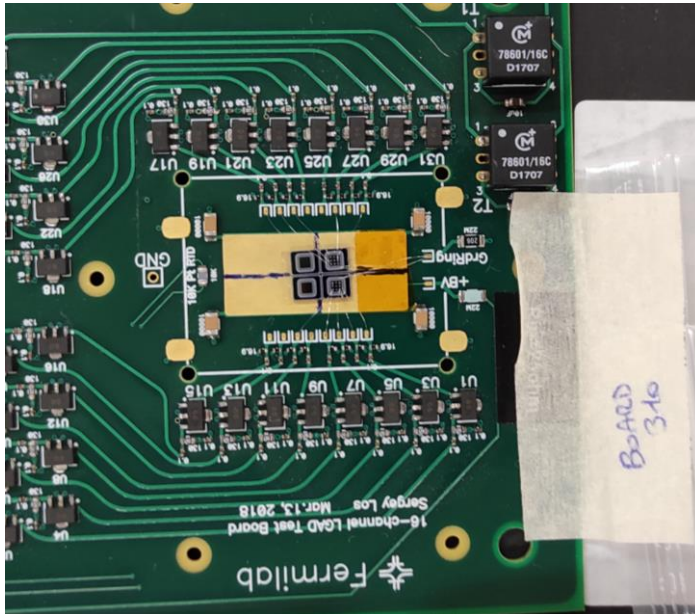
Combining RSD with ^6LiF

Luca Menzio – INFN Torino



AC-LGADs with LiF coating

Luca Menzio – INFN Torino



AC-LGADs with LiF coating: an innovative neutron detector!

- Great timing performances, 40-50 ps
- Optimal spatial resolution, some μm for MIP protons
- LGAD multiplication provides optimal signal/noise
- Carbonated gain implant provides radiation resistance
- Intrinsic photon rejection
 - Photons with energy greater than 20 keV are very unlikely to generate signals in 55 μm thick sensors (1000 μm absorption length)
- Alphas are completely absorbed (15 μm range in silicon)

AC-LGADs with LiF in practice

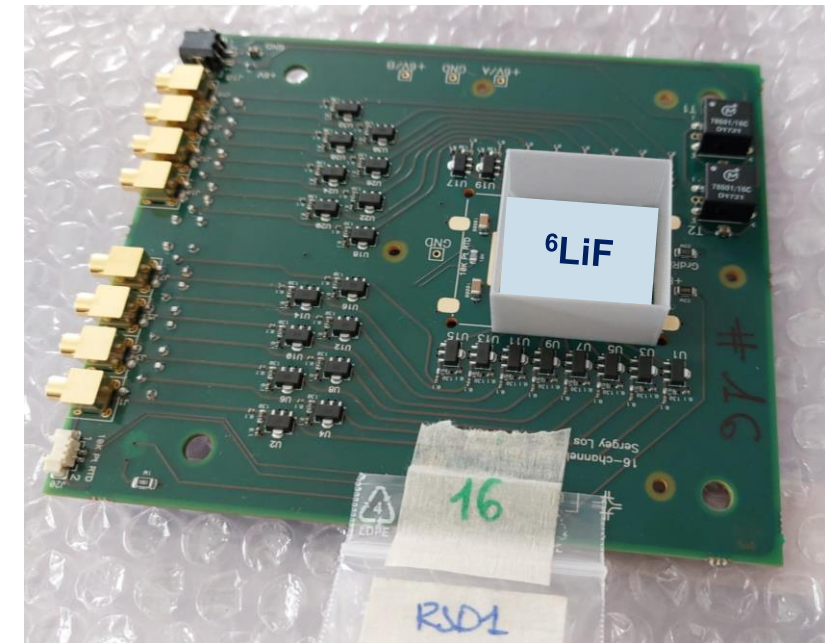
For this first trial three different types of detectors were employed: 50-100, 100-200 and 200-500 FBK AC-LGADs.

Practically, coating these sensors proved difficult because of the many bonds.

Therefore

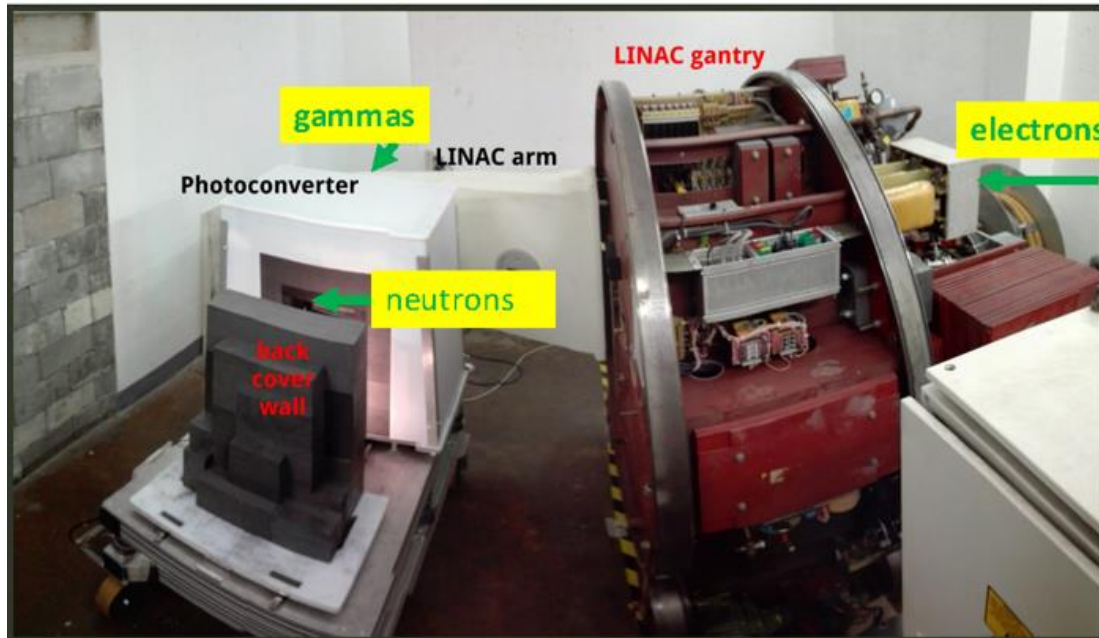
- Bonded the sensors to a 16 channels FNAL board
- Glued 3D printed containment walls outside the bonds area
- Sent the boards to the Frascati Labs to do the ^6LiF deposition

Work in progress! We should receive them back by the end of June



Detector testing

Detectors will be tested in the Turin Thermal Neutron Source.



Based on the Elekta SL18 Precise Linac.

Accelerates electrons (up to 18 MeV) and can be operated in photon mode

A photoconverter provide a testing region with thermal neutrons

Maximum fluence rate:

$$\dot{\Phi}_{th} = (1.75 \pm 0.04) 10^6 \text{ n cm}^{-2} \text{ s}^{-1}$$

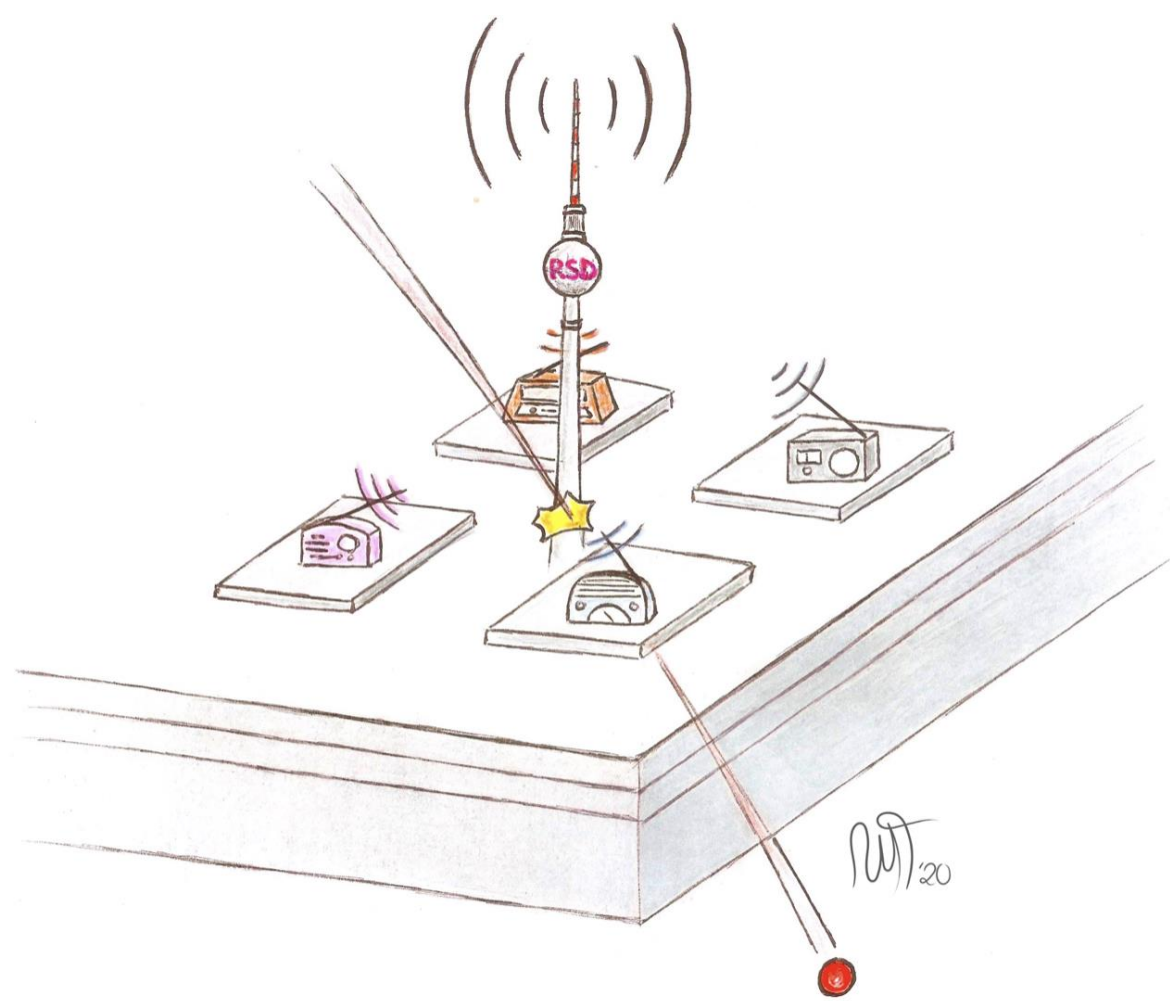
Conclusions

Our group is currently developing a method to detect thermal neutrons with the RSD devices, possibly for neutron imaging.

This detector would provide

- Good radiation resistance
- LGAD-like timing resolution
- Spatial resolution of few microns

First experimental tests are going to be carried out in the next future!



Thank you!

Special Thanks to

We kindly acknowledge the following funding agencies, collaborations:

- INFN - Gruppo V, UFSD and RSD projects
- INFN – FBK agreement on sensor production (convenzione INFN-FBK)
- Horizon 2020, grant UFSD669529
- Dipartimenti di Eccellenza, Univ. of Torino (ex L. 232/2016, art. 1, cc. 314, 337)
- Ministero della Ricerca, Italia , PRIN 2017, progetto 2017L2XKTJ – 4DinSiDe
- Ministero della Ricerca, Italia, FARE, R165xr8frt_fare

References

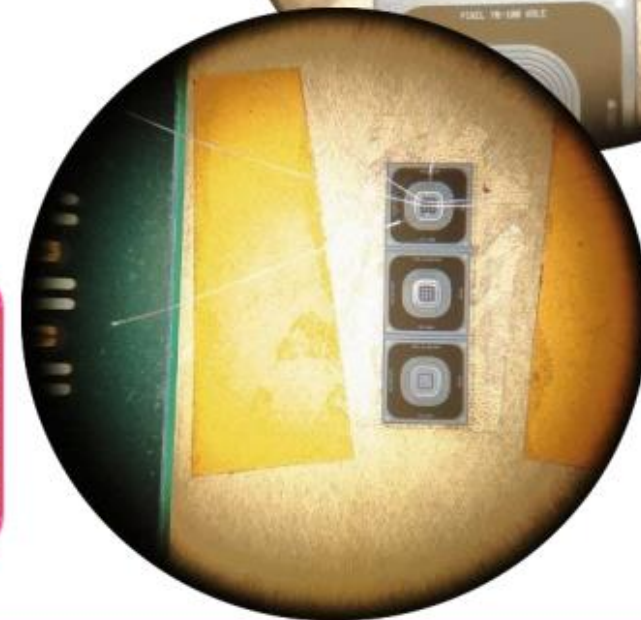
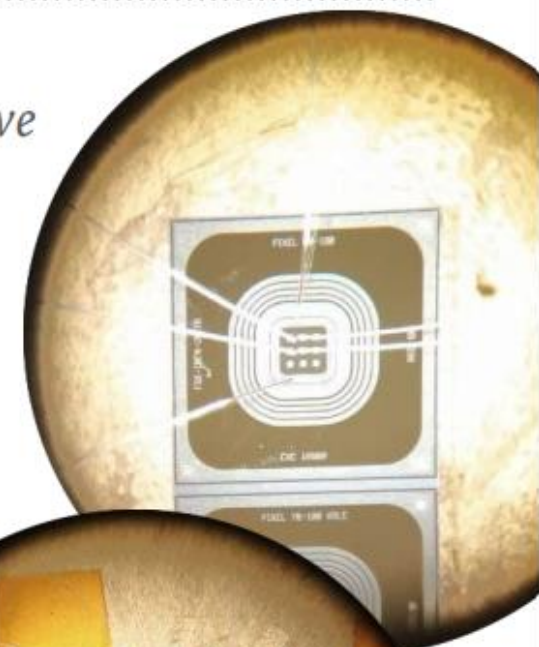
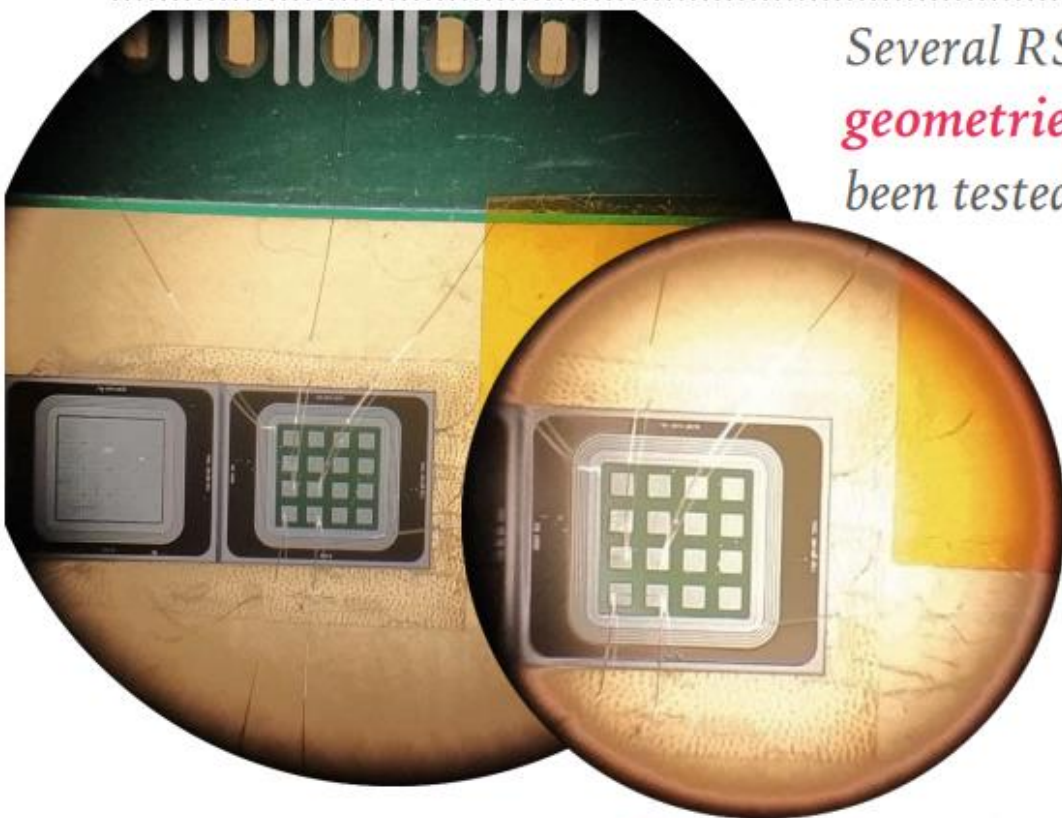
- *Detection system for microimaging with neutrons*, S.H. Williams et al., JINST (2012)
- *Roadmap for High Efficiency Solid-State Neutron Detectors*, R. J. Nikolic et al., Proceedings of SPIE (2005)
- *Resistive AC-Coupled Silicon Detectors: principles of operation and first results from a combined analysis of beam test and laser data*, M. Tornago et al., NIM A (2020).
- *Experimental characterization of semiconductor-based thermalneutron detectors*, R. Bedogni et al., NIM A (2015)
- *A new active neutron detector*, R. Bedogni et al., Radiation Protection Dosimetry (2013)
- *The e_LiBANS facility: A new compact thermal neutron source based on a medical electron LINAC*, V. Monti et al, NIM A (2020)
- *Characterization of large area avalanche photodiodes in X-ray and VUV-light detection*, Luis M. P. Fernandes et al., JINST (2007)

RSD DEVICES UNDER TEST

Several RSD matrices with **different pad-pitch geometries** but same resistivity and oxide thickness have been tested

Pitch dimensions range between 100 and 500 μm

Pads size ranges between 50 and 300 μm



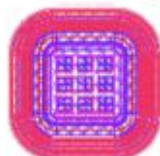
50-100



70-100



100-200



150-200



150-300



200-300



200-500



300-500

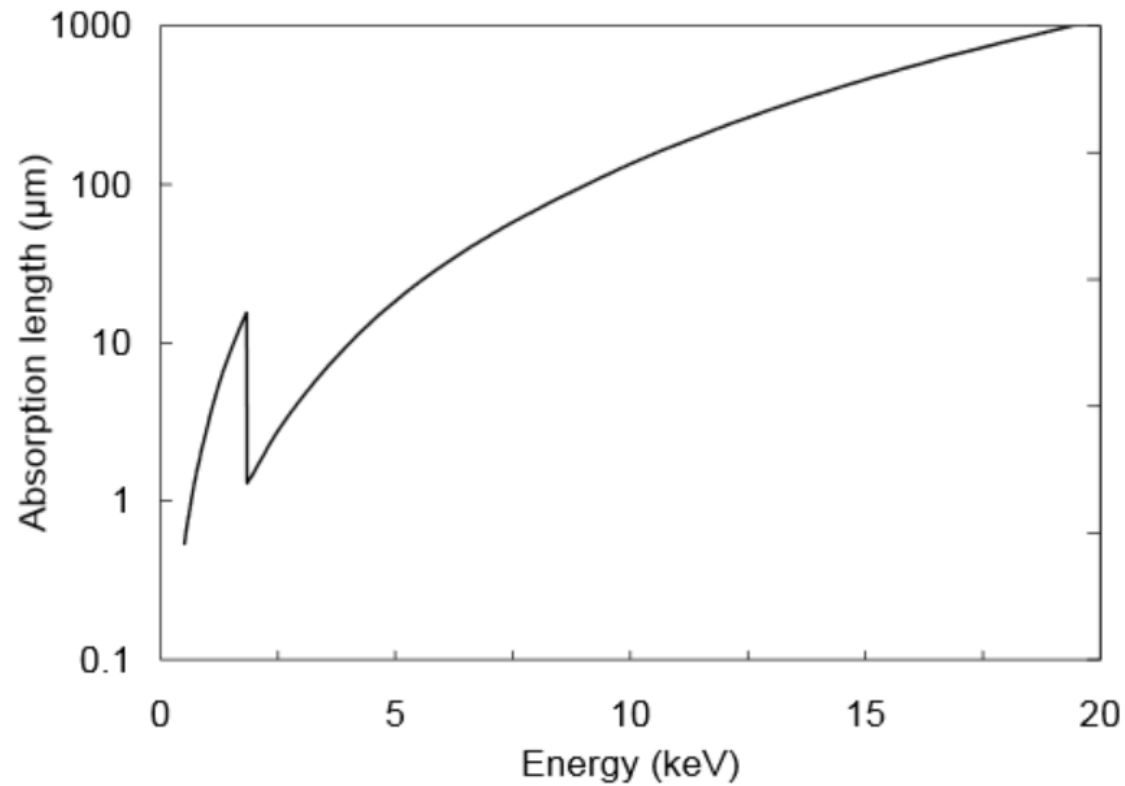
SUMMARY OF 200-UM PITCH RSD TIMING RESOLUTION RESULTS

Timing resolution results are *compatible with the best LGAD performances* obtained at the same gain

	single pad	3 pad	4 pad	
100-200 laser	45 ps	-	22 ps	$\sigma_t^2 = \sigma_{\text{Jitter}}^2$ $\left. \begin{array}{l} \sigma_t^2 = \sigma_{\text{Landau}}^2 + \sigma_{\text{Jitter}}^2 \end{array} \right\}$
100-200 test beam	50 ps	44 ps	-	
190-200 test beam	35 ps	42 ps	-	

Final analysis with amplitude-weighted average

Photon absorption length in silicon



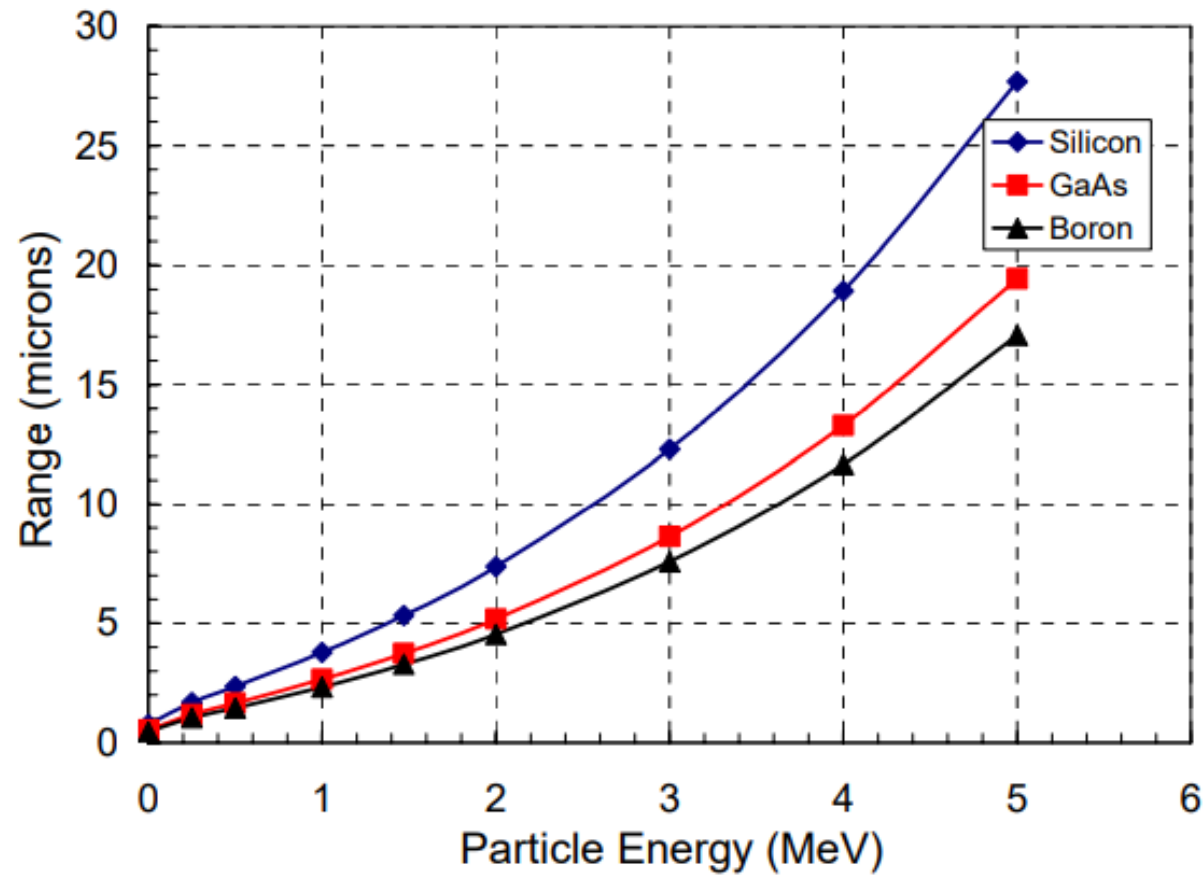


Figure 2 Range of alpha particles in Boron, Silicon and GaAs.

They should be:

- Active
- Low noise
- Minimal sensitivity to Photons
- Small dimension
- Able to measure rates $10^2 - 10^8 \text{ n cm}^{-2} \text{ s}^{-1}$ and resist an integrated Fluence $\sim 10^{13} \text{ n cm}^{-2}$
- Cheap

For absolute and punctual fluence rate measurement common silicon substrate devices like TNRD are suitable.

However long exposures or repetitive ones, force us to explore the use of more radiation resistant material \rightarrow larger Energy gap semiconductor

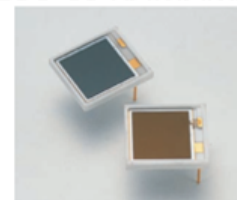
\rightarrow With this aim, Si-carbide (SiC) detectors have been studied

2 substrates have been considered

Si-TNRD



Based on:
S3590-09 HAMAMATSU diodes



Si-Carbide

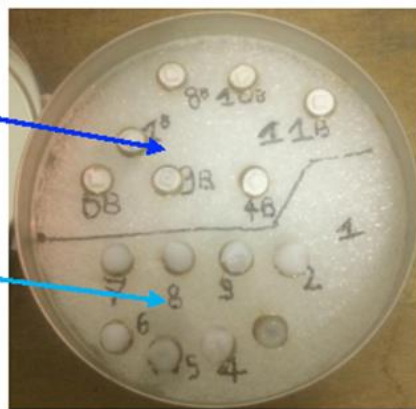
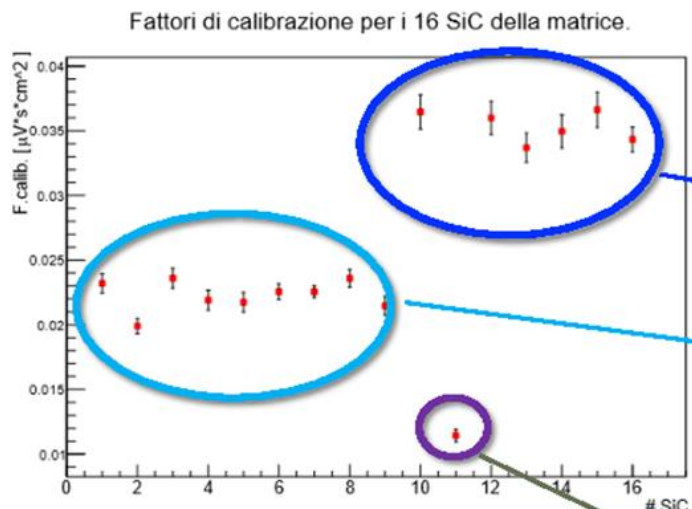


Based on:
SgLux UV photodiodes
Active area: $0.05 - 7.6 \text{ mm}^2$



Appropriate radiator material

Calibration at ENEA Casaccia (RM) TRIGA Reactor (100kW – 1MW)
 1 MW $\rightarrow (1.59 \pm 0.03) 10^6 \text{ cm}^{-2}\text{s}^{-1}$ (Thermal neutron)



irradiated to $5 \times 10^{13} \text{ n cm}^{-2}\text{s}^{-1}$

2 different ^6LiF deposit recipes give different response sensitivity

Calibration accuracy 5-8% being improved

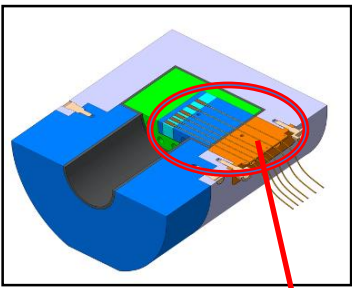


^{137}Cs and ^{60}Co sources



PHOTON SENSITIVITY

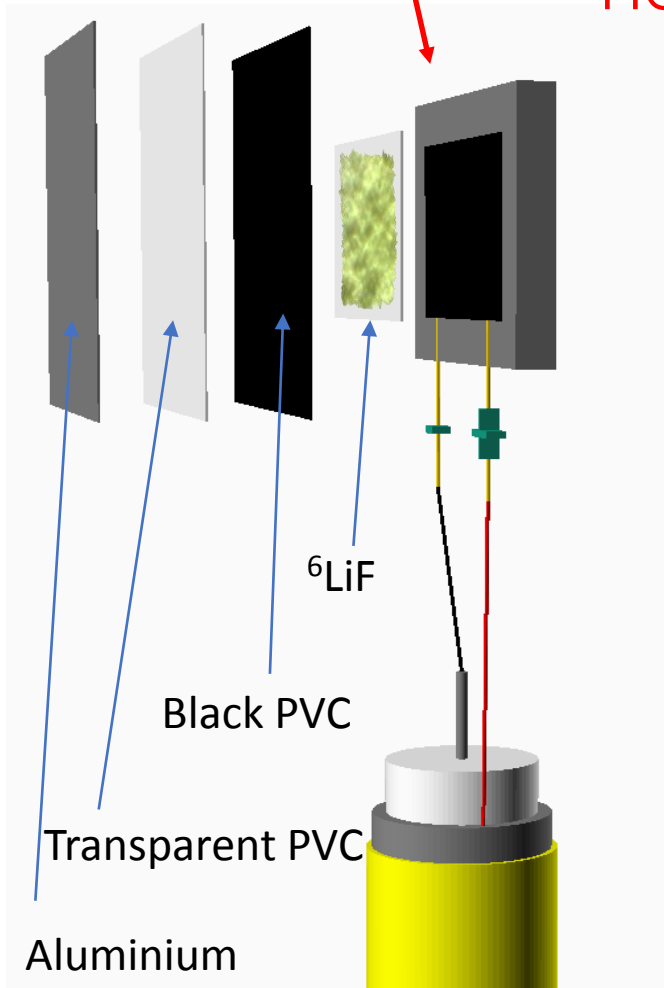
1 unit of thermal fluence rate ($1 \text{ cm}^{-2} \text{ s}^{-1}$) produces a signal equivalent to $70 \mu\text{Gy/h}$ of photon signal
 Photon to neutron sensitivity $\sim 10^{-4}$



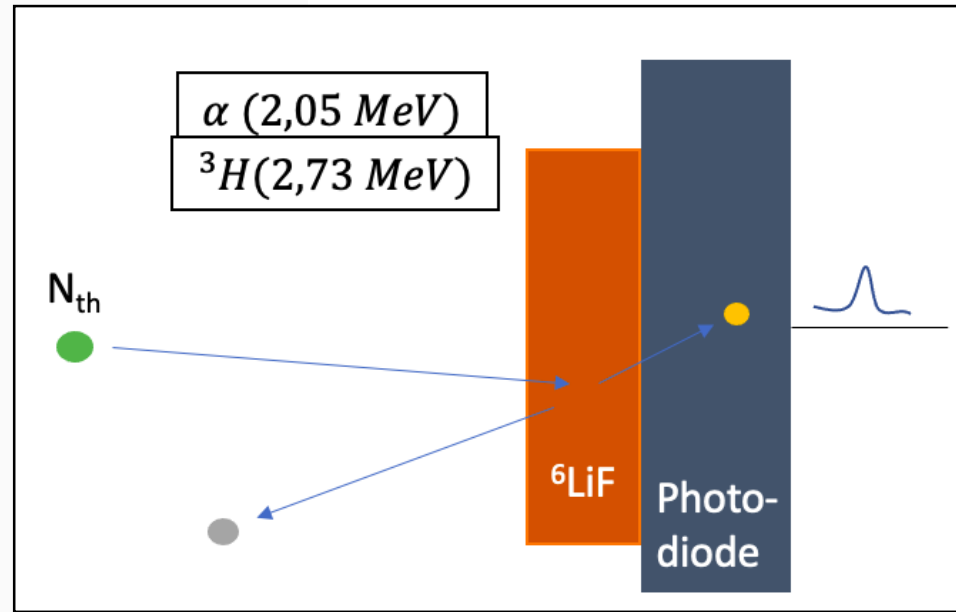
TNPD

(Thermal Neutron Pulse Detector)

How do we measure thermal neutrons?

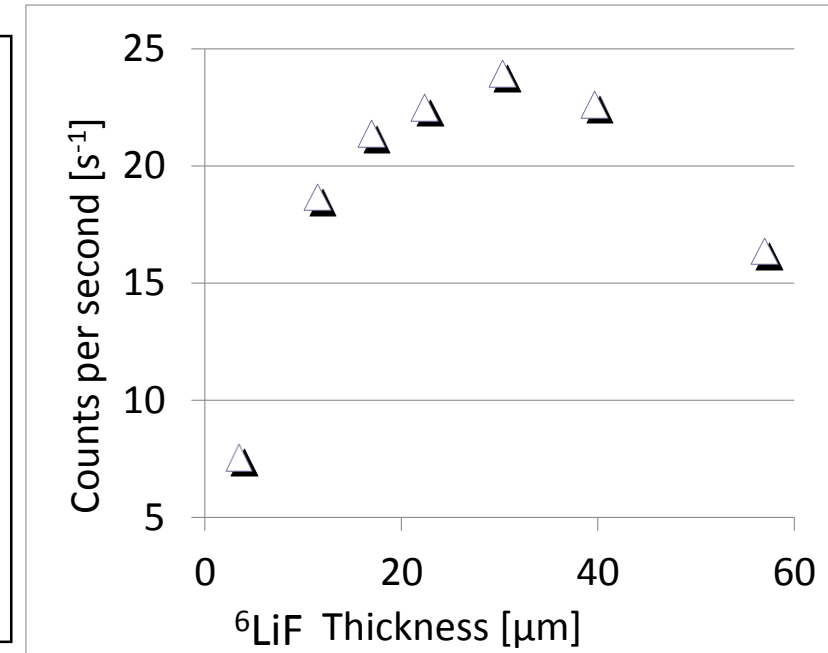


My work



My work

$$\sigma_{th(25meV)} [^6\text{Li}(n, \alpha)^3\text{H}] = 940 \text{ b}$$



My work

Dedicated measure for the determination of the optimal ^6LiF thickness = 30 μm

Absolute comparison between experiment and simulation

$$\dot{N}_{Simulation} = \varepsilon_{TNPD} \cdot \dot{N}_{^6Li(n,\alpha)^3H}$$

$$\left(\frac{\dot{N}_{Experiment}}{\dot{N}_{Simulation}} \right)_{mean} = 1.01 \pm 0.02$$

